

SHINDENGEN

VX-2 Series Power MOSFET

N-Channel Enhancement type

2SK3012
(F16W60VX2)

600V 12A

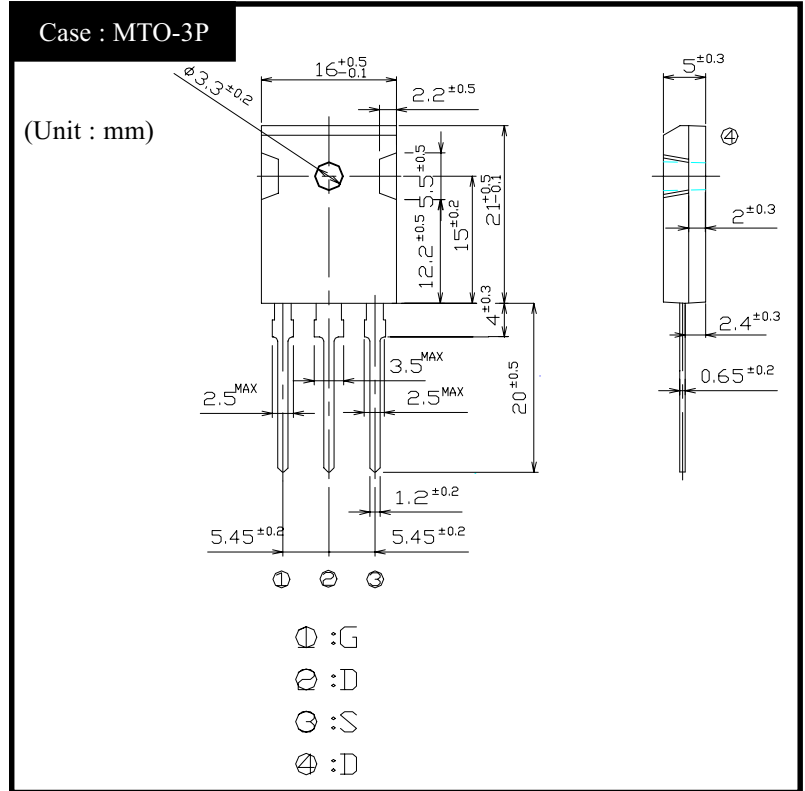
FEATURES

- Input capacitance (Ciss) is small. Especially, input capacitance at 0 bias is small.
- The static Rds(on) is small.
- The switching time is fast.
- Avalanche resistance guaranteed.

APPLICATION

- Switching power supply of AC 100-200V input
- Inverter
- Power Factor Control Circuit

OUTLINE DIMENSIONS



RATINGS

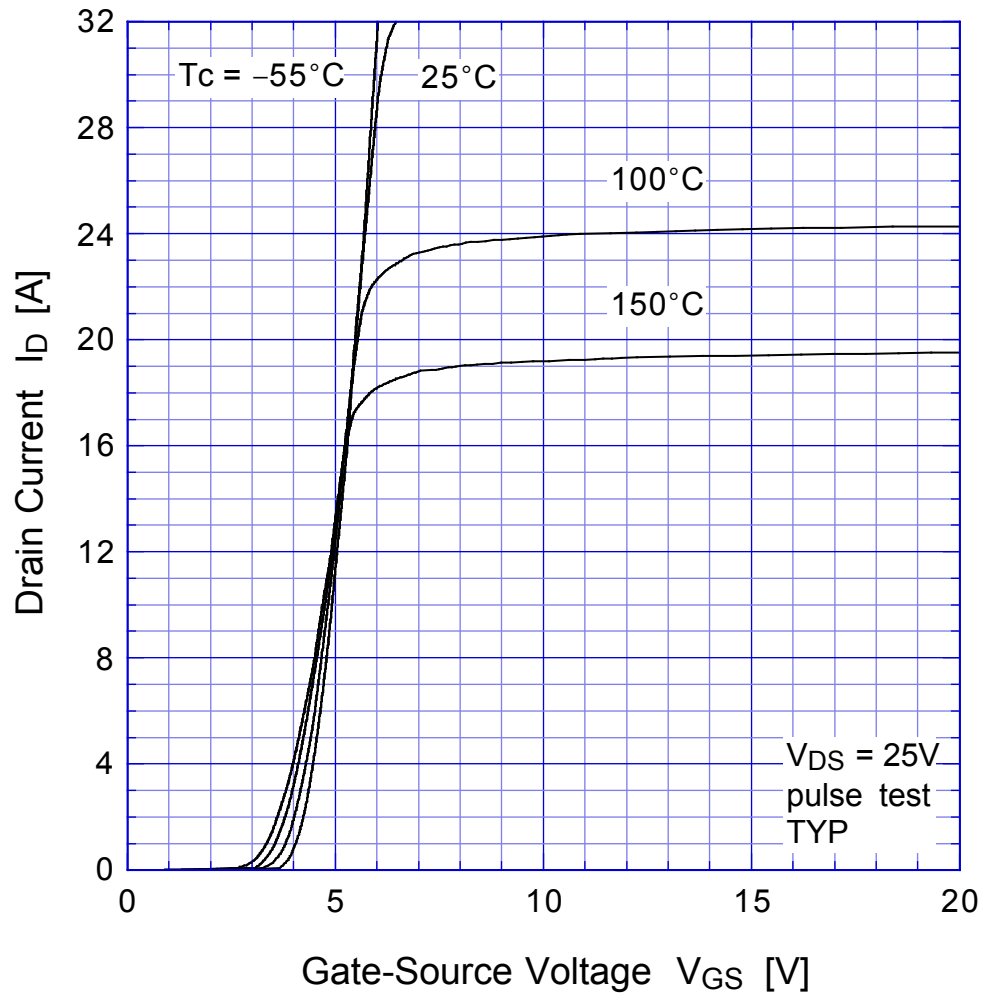
- Absolute Maximum Ratings (Tc = 25°C)

Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	T _{stg}		-55~150	°C
Channel Temperature	T _{ch}		150	
Drain-Source Voltage	V _{DSS}		600	V
Gate-Source Voltage	V _{GSS}		±30	
Continuous Drain Current (DC)	I _D		16	A
Continuous Drain Current (Peak)	I _{DP}		48	
Continuous Source Current (DC)	I _S		16	
Total Power Dissipation	P _T		125	W
Single Pulse Avalanche Current	I _{AS}	T _{ch} = 25°C	16	A
Mounting Torque	TOR	(Recommended torque : 0.5N·m)	0.8	N·m

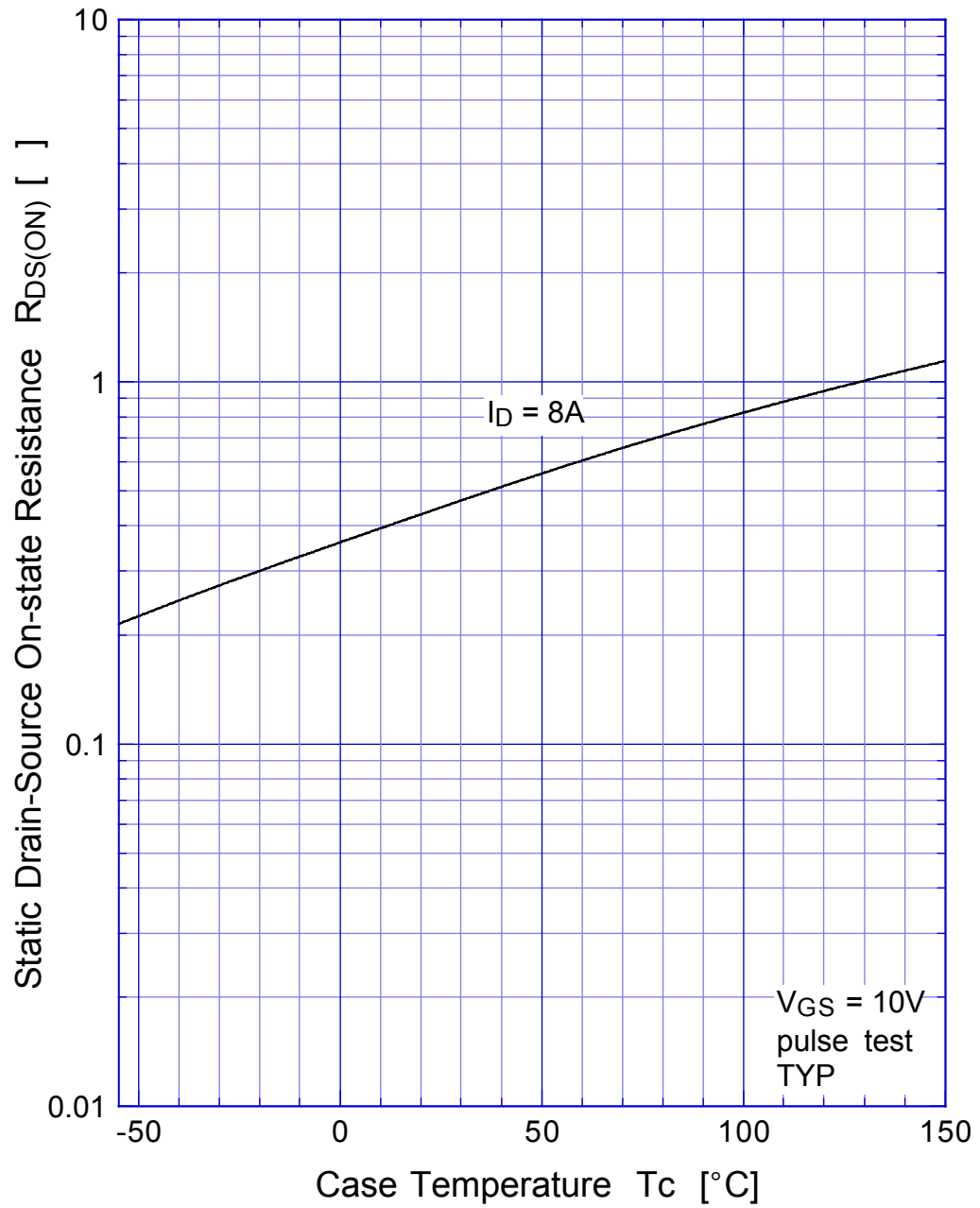
●Electrical Characteristics $T_c = 25^\circ\text{C}$

Item	Symbol	Conditions	Min.	Typ.	Max.	Unit
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D = 1\text{mA}, V_{GS} = 0\text{V}$	600			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 600\text{V}, V_{GS} = 0\text{V}$			250	μA
Gate-Source Leakage Current	I_{GSS}	$V_{GS} = \pm 30\text{V}, V_{DS} = 0\text{V}$			± 0.1	
Forward Transconductance	g_{fs}	$I_D = 8\text{A}, V_{DS} = 10\text{V}$	6.2	10.0		S
Static Drain-Source On-state Resistance	$R_{DS(ON)}$	$I_D = 8\text{A}, V_{GS} = 10\text{V}$		0.45	0.6	Ω
Gate Threshold Voltage	V_{TH}	$I_D = 1\text{mA}, V_{DS} = 10\text{V}$	2.5	3	3.5	V
Source-Drain Diode Forward Voltage	V_{SD}	$I_S = 8\text{A}, V_{GS} = 0\text{V}$			1.5	
Thermal Resistance	θ_{jc}	junction to case			1	$^\circ\text{C}/\text{W}$
Total Gate Charge	Q_g	$V_{GS} = 10\text{V}, I_D = 16\text{A}, V_{DD} = 400\text{V}$		85		nC
Input Capacitance	C_{iss}	$V_{DS} = 10\text{V}, V_{GS} = 0\text{V}, f = 1\text{MHz}$		2300		pF
Reverse Transfer Capacitance	C_{rss}			180		
Output Capacitance	C_{oss}			480		
Turn-On Time	t_{on}	$I_D = 8\text{A}, V_{GS} = 10\text{V}, R_L = 19\Omega$		130	280	ns
Turn-Off Time	t_{off}			260	500	

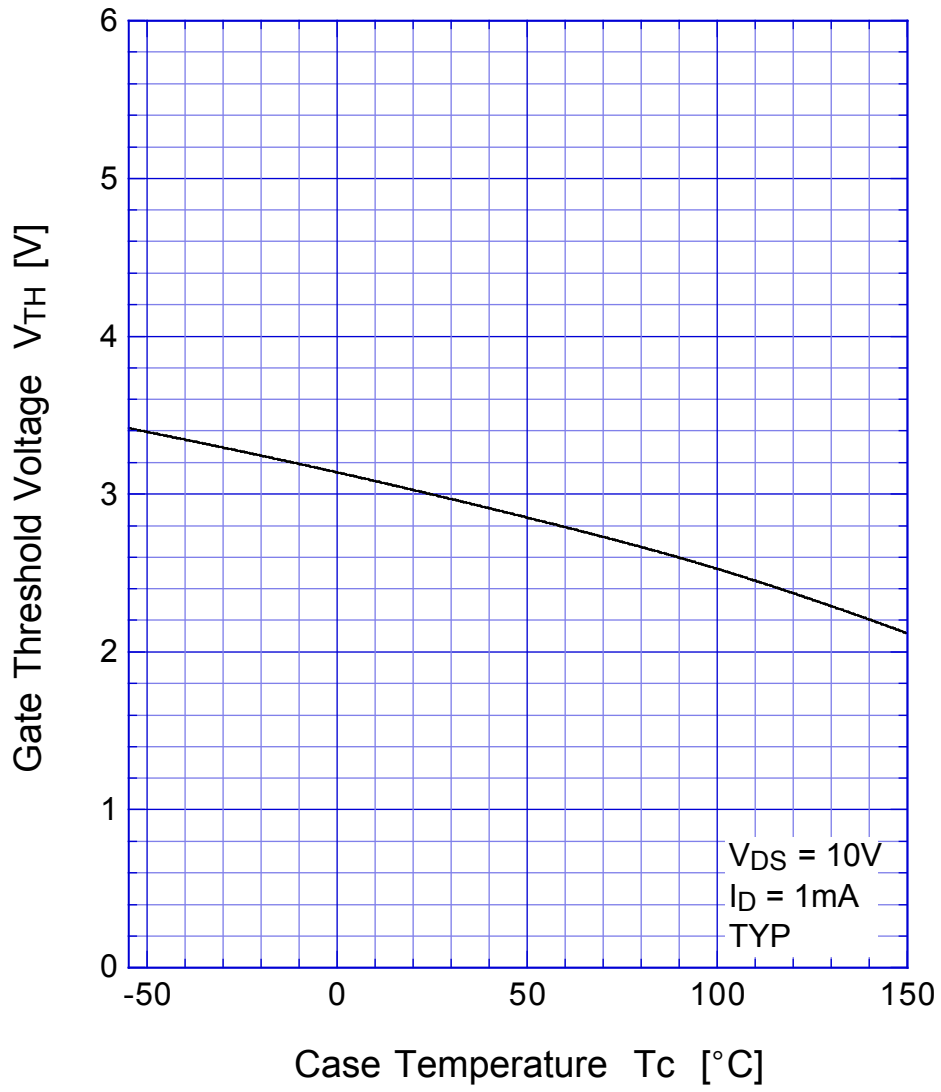
2SK3012 Transfer Characteristics



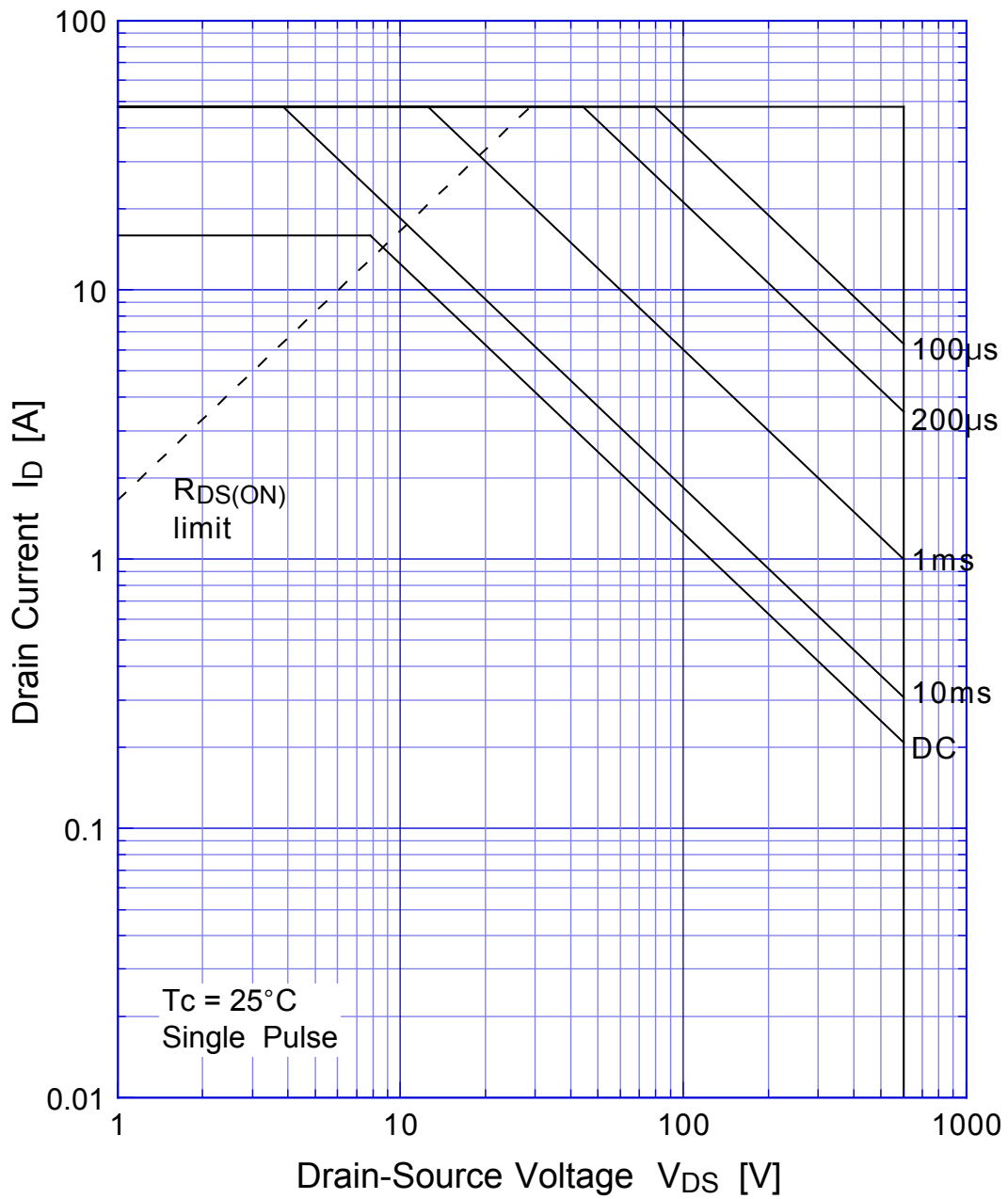
2SK3012 Static Drain-Source On-state Resistance



2SK3012 Gate Threshold Voltage



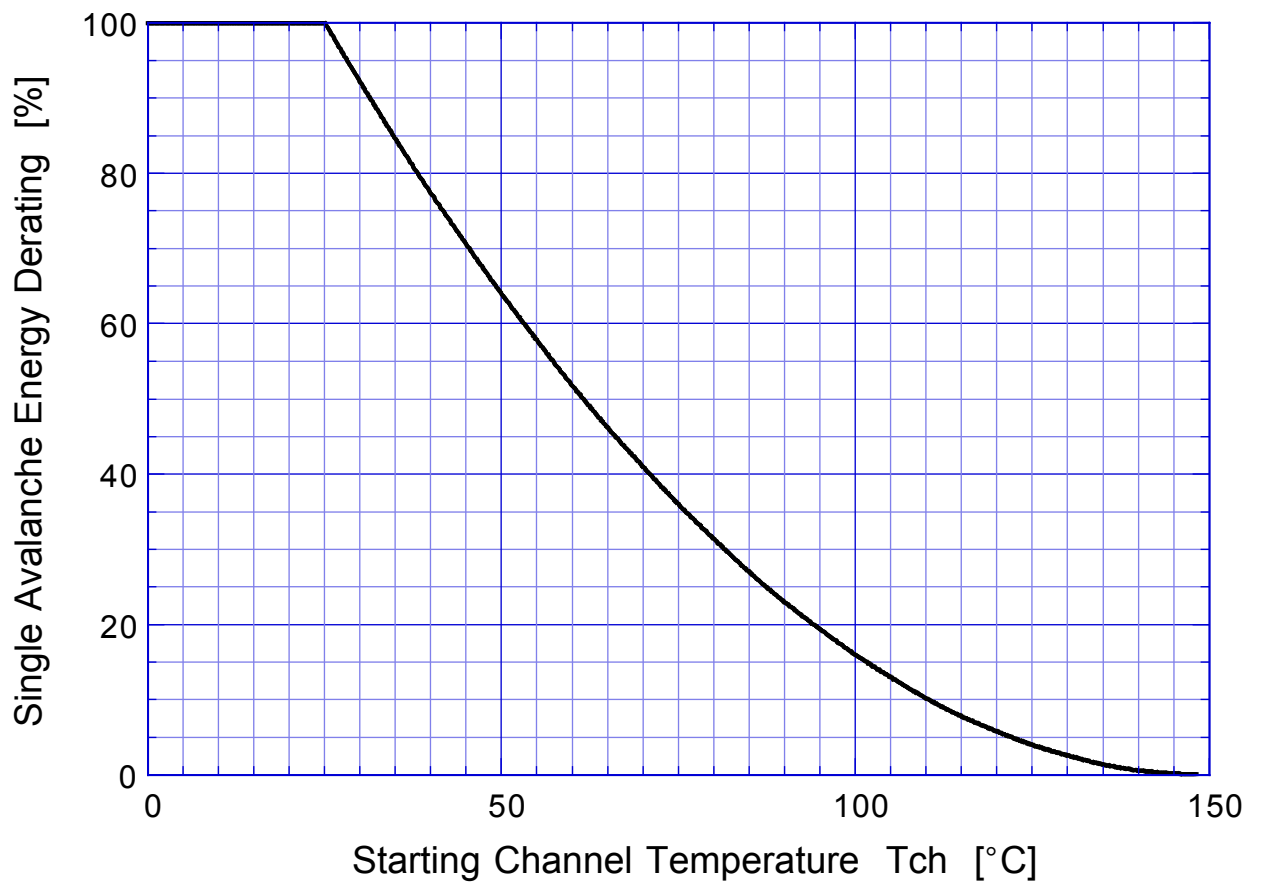
2SK3012 Safe Operating Area



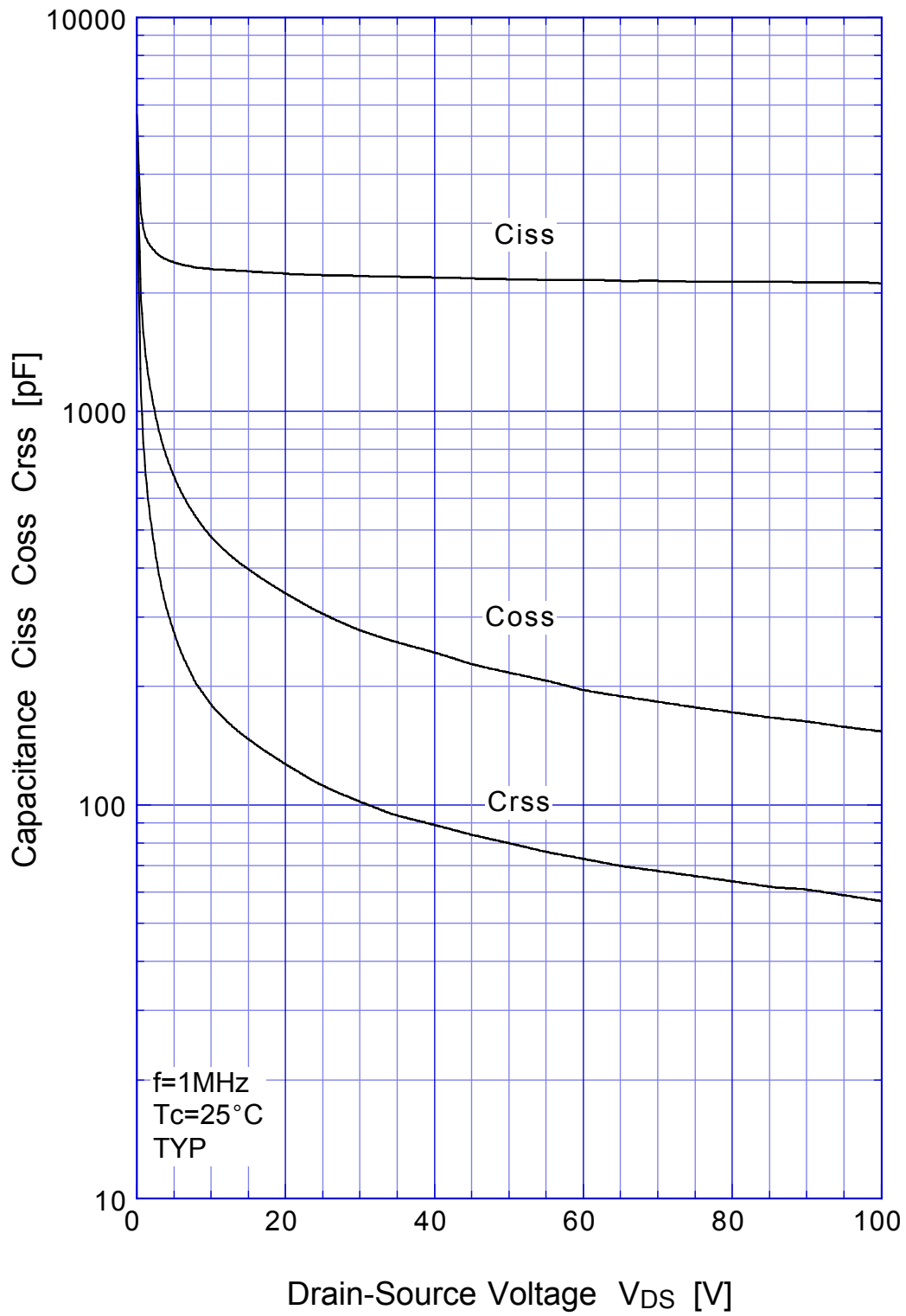
2SK3012 Transient Thermal Impedance



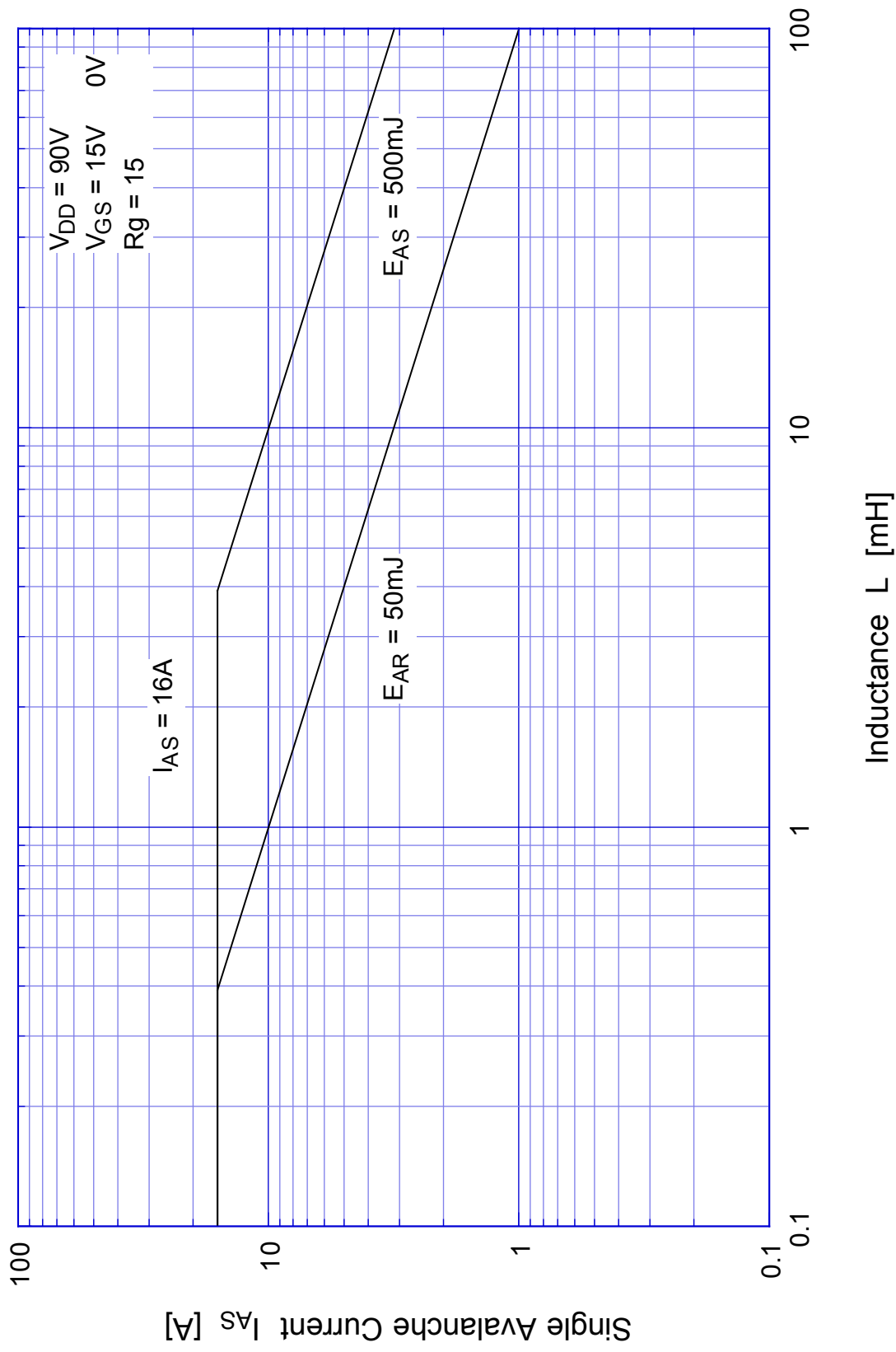
2SK3012 Single Avalanche Energy Derating



2SK3012 Capacitance

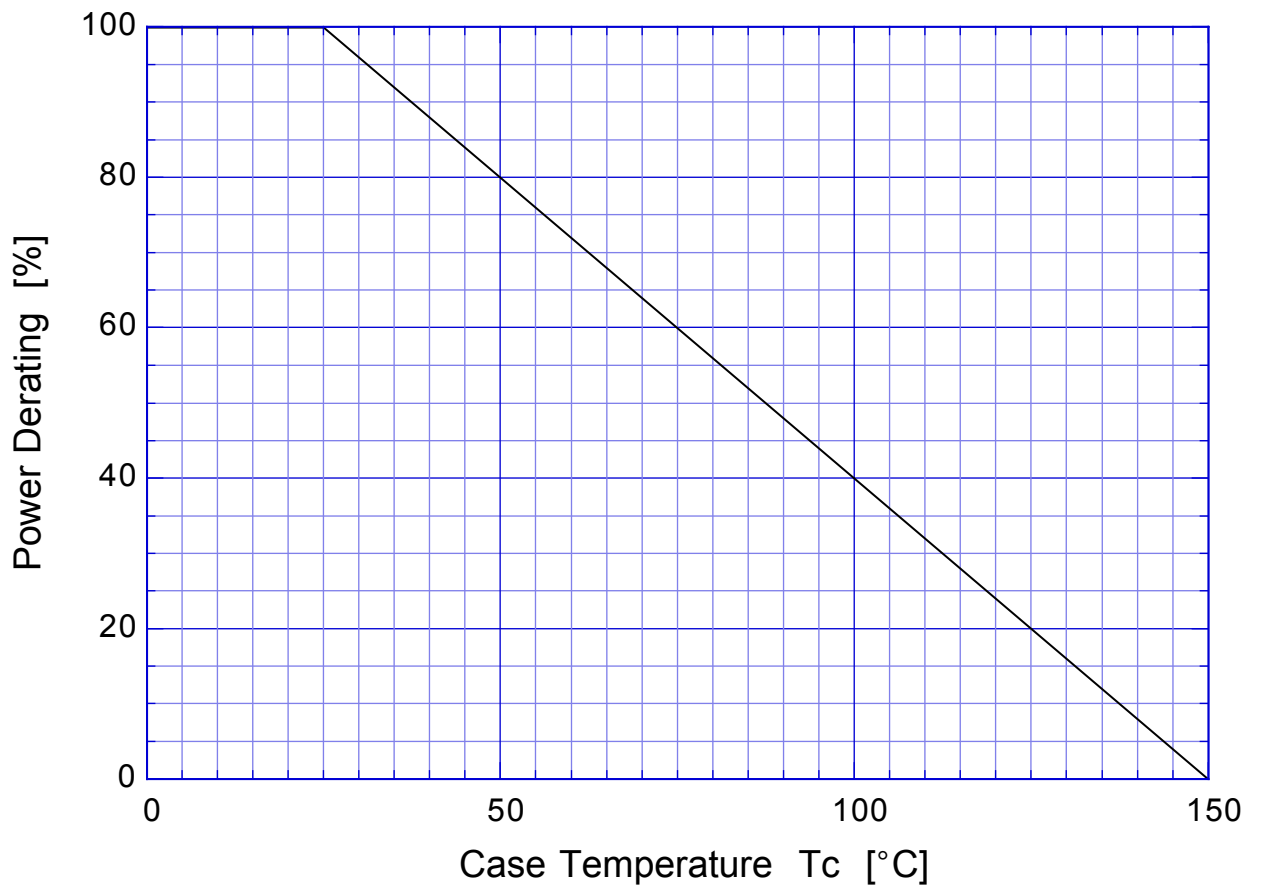


2SK3012 Single Avalanche Current - Inductive Load



2SK3012

Power Derating



2SK3012 Gate Charge Characteristics

